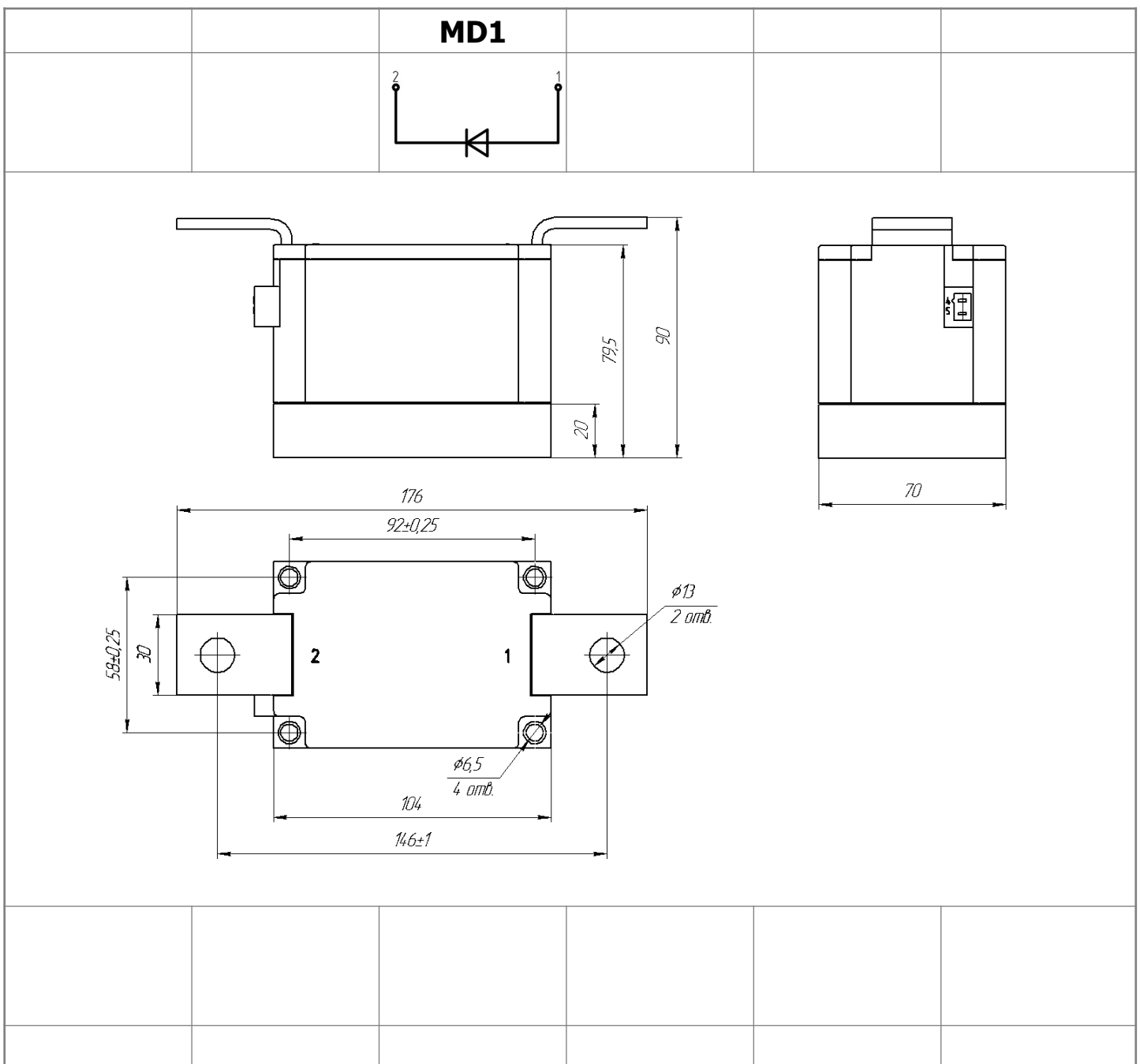


Electrically isolated base plate
 Industrial standard package
 Simplified mechanical design, rapid assembly
 Pressure contact

Single Diode Module For Phase Control MD1-1250-28-E

Average forward current		I_{FAV}		1250 A	
Repetitive peak reverse voltage		V_{RRM}		2000 ÷ 2800 V	
V_{RRM}, V	2000	2200	2400	2600	2800
Voltage code	20	22	24	26	28
$T_j, ^\circ C$	- 40 ÷ 160				




All dimensions in millimeters (inches)

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	1250	$T_c = 91\text{ }^\circ\text{C}$; 180° half-sine wave; 50 Hz
I_{FRMS}	RMS forward current	A	1962	
I_{FSM}	Surge forward current	kA	36.0 43.0	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			38.0 46.0	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
I^2t	Safety factor	$A^2s \cdot 10^3$	6400 9200	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			5900 8700	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	2000÷2800	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	2100÷2900	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; single pulse;
V_R	Reverse continuous voltages	V	$0.6 \cdot V_{RRM}$	$T_j = T_{j\text{ max}}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ\text{C}$	- 40 ÷ 50	
T_j	Operating junction temperature	$^\circ\text{C}$	- 40 ÷ 160	
$T_{c\text{ op}}$	Operating temperature	$^\circ\text{C}$	- 40 ÷ 125	
MECHANICAL				
a	Acceleration under vibration	m/s^2	50	

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	1.38	$T_j = 25\text{ }^\circ\text{C}$; $I_{FM} = 3140\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.80	$T_j = T_{j\text{ max}}$;
r_T	Forward slope resistance, max	$\text{m}\Omega$	0.170	$0.5 \pi I_{FAV} < I_T < 1.5 \pi I_{FAV}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	70	$T_j = T_{j\text{ max}}$; $V_R = V_{RRM}$
THERMAL				
R_{thjc}	Thermal resistance, junction to case			180° half-sine wave, 50 Hz
	per module	$^\circ\text{C/W}$	0.0420	
R_{thch}	Thermal resistance, case to heatsink			
	per module	$^\circ\text{C/W}$	0.0100	
INSULATION				
V_{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS
			3.60	
MECHANICAL				
M_1	Mounting torque (M6) ¹⁾	Nm	6.00	Tolerance $\pm 15\%$
M_2	Terminal connection torque (M12) ¹⁾	Nm	18.00	Tolerance $\pm 10\%$
w	Weight, max	g	2250	

PART NUMBERING GUIDE							NOTES			
MD	1	-	1250	-	28	-	E	-	N	1) The screws must be lubricated
1	2		3		4		5		6	
1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.E) 6. Ambient Conditions: N – Normal										
		UL certified file-No. E255404								